

# ADD-A-PAK Generation VII Power Modules Thyristor/Thyristor, 95 A



PRODUCT SUMMARY					
I <sub>T(AV)</sub>	95 A				

#### **MECHANICAL DESCRIPTION**

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

#### **FEATURES**

- · High voltage
- Industrial standard package
- · Low thermal resistance
- UL approved file E78996
- Compliant to RoHS directive 2002/95/EC
- · Designed and qualified for industrial level

#### **BENEFITS**

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- · High surge capability
- Easy mounting on heatsink

#### **ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	RACTERISTICS VALUES					
I <sub>T(AV)</sub>	85 °C	95					
I <sub>T(RMS)</sub>		150	Δ				
1	50 Hz	2000	Α				
I <sub>TSM</sub>	60 Hz	2094					
l²t	50 Hz	20	kA <sup>2</sup> s				
1-1	60 Hz	18.26	KA-S				
l <sup>2</sup> √t		200	kA <sup>2</sup> √s				
V <sub>RRM</sub>	Range	400 to 1600	V				
T <sub>Stg</sub>		- 40 to 125	°C				
TJ		- 40 (0 125					

## VSKU91.., VSKV91.. Series

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#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V	I <sub>RRM,</sub> I <sub>DRM</sub> AT 125 °C mA				
	04	400	500	400					
VSK.91	08	800	900	800	15				
12		1200	1300	1200	13				
	16	1600	1700	1600					

ON-STATE CONDUCTION						
PARAMETER	SYMBOL		VALUES	UNITS		
Maximum average on-state current	I <sub>T(AV)</sub>	180° conduction T <sub>C</sub> = 85 °C	95	А		
Maximum continuous RMS on-state current		DC			150	
Maximum continuous Rivis on-state current	I <sub>T(RMS)</sub>	T <sub>C</sub>			78	°C
		t = 10 ms	No voltage		2000	
Maximum peak, one-cycle non-repetitive		t = 8.3 ms	reapplied	Sinusoidal	2094	•
on-state current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	half wave, initial $T_{.1} = T_{.1}$ maximum	1682	A
		t = 8.3 ms	reapplied		1760	
		t = 10 ms	No voltage		20	kA <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 8.3 ms	reapplied	Initial T <sub>J</sub> = T <sub>J</sub> maximum	18.26	
		t = 10 ms	100 % V <sub>RRM</sub>		14.14	
		t = 8.3 ms	reapplied		12.91	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t <sup>(1)</sup>	t = 0.1  ms to  1000  ms $T_J = T_J \text{ maximum}$	200	kA²√s		
Marine and a sittle school of the second	V (2)	Low level (3)			0.97	
Maximum value of threshold voltage	V <sub>T(TO)</sub> (2)	High level (4)	$T_J = T_J \text{ maxin}$	num	1.1	V
Maximum value of on-state	(2)	Low level (3)			2.76	_
slope resistance	r <sub>t</sub> <sup>(2)</sup>	High level (4)	$T_J = T_J \text{ maxin}$	num	2.38	mΩ
Maximum on-state voltage drop	$V_{TM}$	$I_{TM} = \pi \times I_{T(AV)}$	T <sub>J</sub> = 25 °C		1.73	V
Maximum non-repetitive rate of rise of	dl/dt	$T_J = 25$ °C, from	150	A/µs		
turned on current	ui/ut	$I_{TM} = \pi \times I_{T(AV)}, I_g = 500 \text{ mA}, t_r < 0.5  \mu\text{s}, t_p > 6  \mu\text{s}$				7ν μο
Maximum holding current	I <sub>H</sub>	T <sub>J</sub> = 25 °C, and resistive load, q	250	mA		
Maximum latching current	ΙL	$T_J = 25 ^{\circ}\text{C}$ , and	ode supply = 6 \	/, resistive load	400	

- (1)  $I^2t$  for time  $t_x = I^2\sqrt{t} \times \sqrt{t_x}$
- (2) Average power =  $V_{T(TO)} \times I_{T(AV)} + r_t \times (I_{T(RMS)})^2$ (3) 16.7 %  $\times \pi \times I_{AV} < I < \pi \times I_{AV}$
- $^{(4)}$   $I > \pi \times I_{AV}$



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TRIGGERING					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum peak gate power	P <sub>GM</sub>			12	W
Maximum average gate power	P <sub>G(AV)</sub>			3.0	VV
Maximum peak gate current	I <sub>GM</sub>			3.0	А
Maximum peak negative gate voltage	- V <sub>GM</sub>			10	
Maximum gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Anode supply = 6 V	4.0	V
		T <sub>J</sub> = 25 °C		2.5	
		T <sub>J</sub> = 125 °C	- resistive load	1.7	
		T <sub>J</sub> = - 40 °C		270	mA
Maximum gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = 25 °C	Anode supply = 6 V resistive load	150	
		T <sub>J</sub> = 125 °C	- resistive load	80	
Maximum gate voltage that will not trigger	$V_{\sf GD}$	T <sub>J</sub> = 125 °C, rated V <sub>DRM</sub> applied		0.25	V
Maximum gate current that will not trigger	I <sub>GD</sub>	$T_J = 125 ^{\circ}\text{C}$ , rated $V_{DR}$	6	mA	

BLOCKING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum peak reverse and off-state leakage current at V <sub>RRM</sub> , V <sub>DRM</sub>	I <sub>RRM,</sub> I <sub>DRM</sub>	T <sub>J</sub> = 125 °C, gate open circuit	15	mA				
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz	3000 (1 min) 3600 (1 s)	V				
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J$ = 125 °C, linear to 0.67 $V_{DRM}$	1000	V/µs				

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Junction operating and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 125	°C		
Maximum internal thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.22	°C/W		
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>	Mounting surface flat, smooth and greased	0.1	C/VV		
Mounting torque ± 10 % to heatsin			A mounting compound is recommended and the torque should be rechecked after a period of	4	Nm		
			3 hours to allow for the spread of the compound.	3	Niii		
Approximate weight				75	g		
Approximate weight				2.7	OZ.		
Case style			JEDEC	TO-240AA	compatible		

∆R CONDUCTION PER JUNCTION											
DEVICES	SINE HALF WAVE CONDUCTION RECTANGULAR WAVE CONDUCTION							UNITS			
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.91	0.04	0.048	0.063	0.085	0.125	0.033	0.052	0.067	0.088	0.127	°C/W

#### Note

• Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

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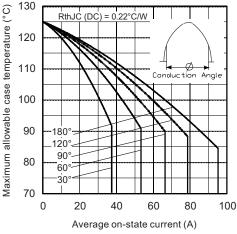


Fig. 1 - Current Ratings Characteristics

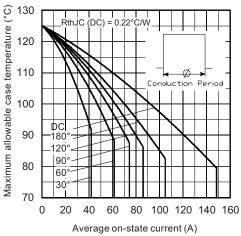


Fig. 2 - Current Ratings Characteristics

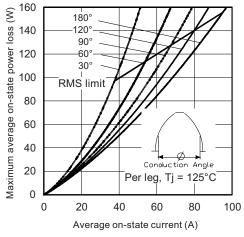


Fig. 3 - On-State Power Loss Characteristics

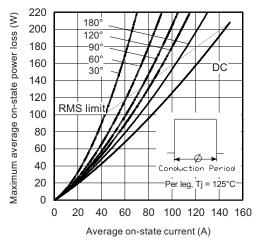


Fig. 4 - On-State Power Loss Characteristics

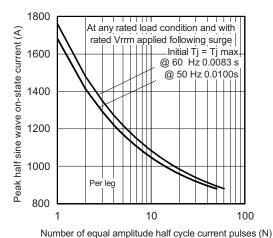


Fig. 5 - Maximum Non-Repetitive Surge Current

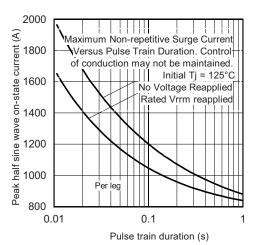


Fig. 6 - Maximum Non-Repetitive Surge Current



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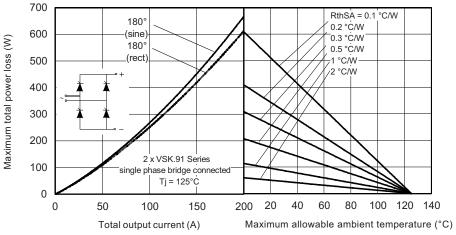


Fig. 7 - On-State Power Loss Characteristics

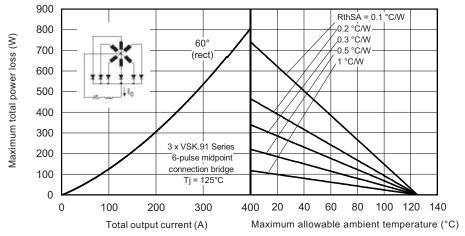


Fig. 8 - On-State Power Loss Characteristics

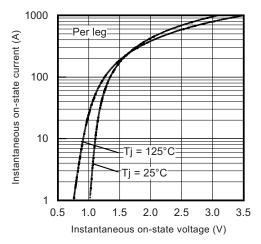


Fig. 9 - On-State Voltage Characteristics

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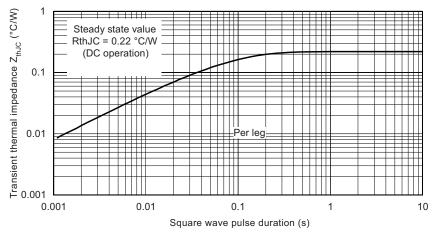
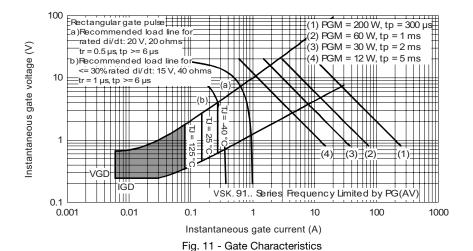


Fig. 10 - Thermal Impedance  $Z_{\text{thJC}}$  Characteristics



#### **ORDERING INFORMATION TABLE**

- 1 Module type
- 2 Circuit configuration (see end of datasheet)
- Current code (95 A)
- 4 Voltage code (see Voltage Ratings table)

#### Note

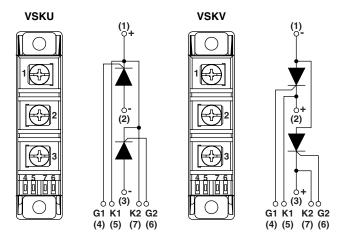
• To order the optional hardware go to <a href="https://www.vishay.com/doc?95172">www.vishay.com/doc?95172</a>





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#### **CIRCUIT CONFIGURATION**

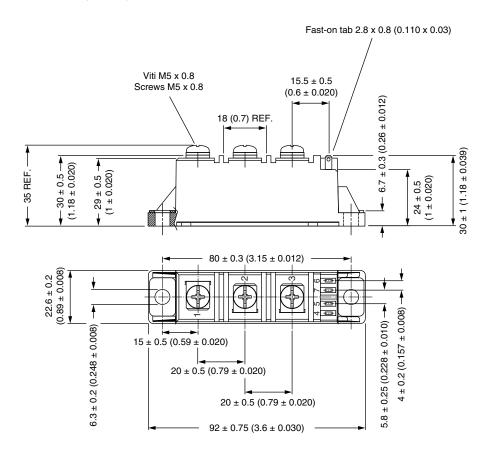


LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95368				



### **ADD-A-PAK Generation VII - Thyristor**

#### **DIMENSIONS** in millimeters (inches)





### **Legal Disclaimer Notice**

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